

High Power NPN Silicon Power Transistors

... designed for linear amplifiers, series pass regulators, and inductive switching applications.

- Forward Biased Second Breakdown Current Capability
 $I_{S/b} = 3.75 \text{ Adc @ } V_{CE} = 40 \text{ Vdc} \text{ — } 2N3771$
 $= 2.5 \text{ Adc @ } V_{CE} = 60 \text{ Vdc} \text{ — } 2N3772$

*MAXIMUM RATINGS

Rating	Symbol	2N3771	2N3772	Unit
Collector-Emitter Voltage	V_{CEO}	40	60	Vdc
Collector-Emitter Voltage	V_{CEX}	50	80	Vdc
Collector-Base Voltage	V_{CB}	50	100	Vdc
Emitter-Base Voltage	V_{EB}	5.0	7.0	Vdc
Collector Current — Continuous Peak	I_C	30 30	20 30	Adc
Base Current — Continuous Peak	I_B	7.5 15	5.0 15	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	150 0.855		Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristics	Symbol	2N3771, 2N3772	Unit
Thermal Resistance, Junction to Case	θ_{JC}	1.17	$^\circ\text{C/W}$

* Indicates JEDEC Registered Data.

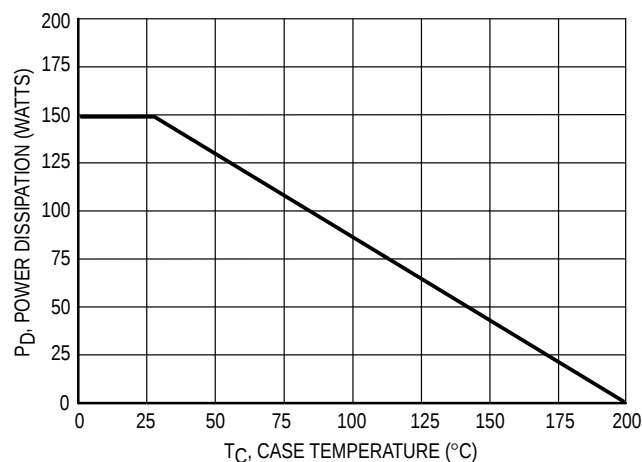


Figure 1. Power Derating

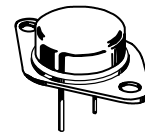
Preferred devices are Motorola recommended choices for future use and best overall value.

REV 7

2N3771*
2N3772

*Motorola Preferred Device

**20 and 30 AMPERE
POWER TRANSISTORS
NPN SILICON
40 and 60 VOLTS
150 WATTS**



**CASE 1-07
TO-204AA
(TO-3)**

2N3771 2N3772

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
*Collector–Emitter Sustaining Voltage (1) (I _C = 0.2 Adc, I _B = 0)	2N3771 2N3772	V _{CEO(sus)}	40 60	— —	Vdc
Collector–Emitter Sustaining Voltage (I _C = 0.2 Adc, V _{EB(off)} = 1.5 Vdc, R _{BE} = 100 Ohms)	2N3771 2N3772	V _{CEX(sus)}	50 80	— —	Vdc
Collector–Emitter Sustaining Voltage (I _C = 0.2 Adc, R _{BE} = 100 Ohms)	2N3771 2N3772	V _{CER(sus)}	45 70	— —	Vdc
*Collector Cutoff Current (V _{CE} = 30 Vdc, I _B = 0) (V _{CE} = 50 Vdc, I _B = 0) (V _{CE} = 25 Vdc, I _B = 0)	2N3771 2N3772	I _{CEO}	— —	10 10	mAdc
*Collector Cutoff Current (V _{CE} = 50 Vdc, V _{EB(off)} = 1.5 Vdc) (V _{CE} = 100 Vdc, V _{EB(off)} = 1.5 Vdc) (V _{CE} = 45 Vdc, V _{EB(off)} = 1.5 Vdc) (V _{CE} = 30 Vdc, V _{EB(off)} = 1.5 Vdc, T _C = 150°C) (V _{CE} = 45 Vdc, V _{EB(off)} = 1.5 Vdc, T _C = 150°C)	2N3771 2N3772 2N6257 2N3771 2N3772	I _{CEV}	— — — — —	2.0 5.0 4.0 10 10	mAdc
*Collector Cutoff Current (V _{CB} = 50 Vdc, I _E = 0) (V _{CB} = 100 Vdc, I _E = 0)	2N3771 2N3772	I _{CBO}	— —	2.0 5.0	mAdc
*Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0) (V _{BE} = 7.0 Vdc, I _C = 0)	2N3771 2N3772	I _{EBO}	— —	5.0 5.0	mAdc
*ON CHARACTERISTICS					
DC Current Gain (1) (I _C = 15 Adc, V _{CE} = 4.0 Vdc) (I _C = 10 Adc, V _{CE} = 4.0 Vdc) (I _C = 8.0 Adc, V _{CE} = 4.0 Vdc) (I _C = 30 Adc, V _{CE} = 4.0 Vdc) (I _C = 20 Adc, V _{CE} = 4.0 Vdc)	2N3771 2N3772 2N3771 2N3772	h _{FE}	15 15 5.0 5.0	60 60 — —	—
Collector–Emitter Saturation Voltage (I _C = 15 Adc, I _B = 1.5 Adc) (I _C = 10 Adc, I _B = 1.0 Adc) (I _C = 30 Adc, I _B = 6.0 Adc) (I _C = 20 Adc, I _B = 4.0 Adc)	2N3771 2N3772 2N3771 2N3772	V _{CE(sat)}	— — — —	2.0 1.4 4.0 4.0	Vdc
Base–Emitter On Voltage (I _C = 15 Adc, V _{CE} = 4.0 Vdc) (I _C = 10 Adc, V _{CE} = 4.0 Vdc) (I _C = 8.0 Adc, V _{CE} = 4.0 Vdc)	2N3771 2N3772	V _{BE(on)}	— —	2.7 2.2	Vdc
*DYNAMIC CHARACTERISTICS					
Current–Gain — Bandwidth Product (I _C = 1.0 Adc, V _{CE} = 4.0 Vdc, f _{test} = 50 kHz)		f _T	0.2	—	MHz
Small–Signal Current Gain (I _C = 1.0 Adc, V _{CE} = 4.0 Vdc, f = 1.0 kHz)		h _{fe}	40	—	—
SECOND BREAKDOWN					
Second Breakdown Energy with Base Forward Biased, t = 1.0 s (non–repetitive) (V _{CE} = 40 Vdc) (V _{CE} = 60 Vdc)	2N3771 2N3772	I _{S/b}	3.75 2.5	— —	Adc

* Indicates JEDEC Registered Data.

(1) Pulse Test: 300 μs, Rep. Rate 60 cps.

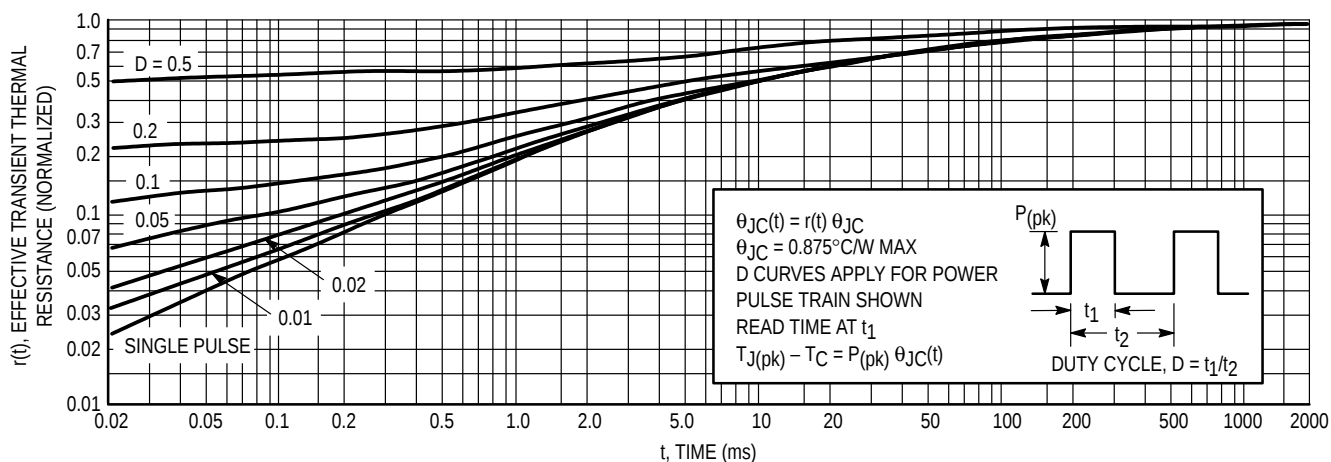


Figure 2. Thermal Response — 2N3771, 2N3772

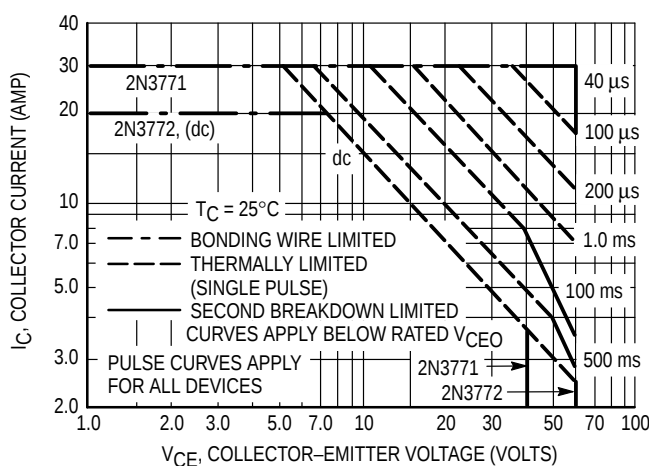


Figure 3. Active-Region Safe Operating Area — 2N3771, 2N3772

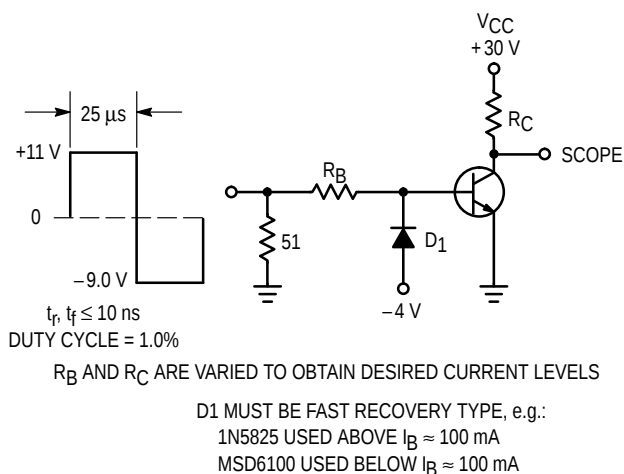


Figure 4. Switching Time Test Circuit

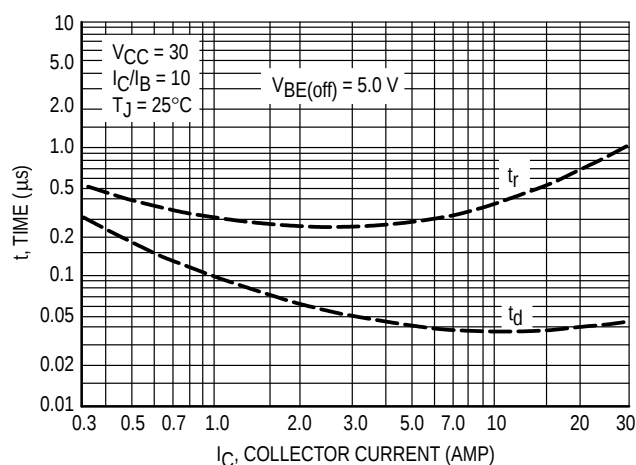


Figure 5. Turn-On Time

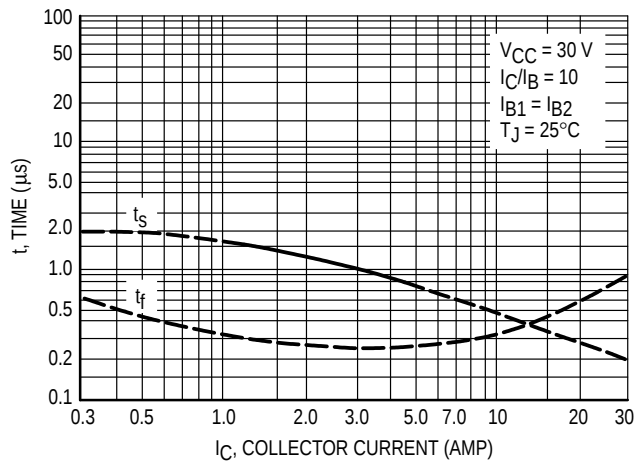


Figure 6. Turn-Off Time

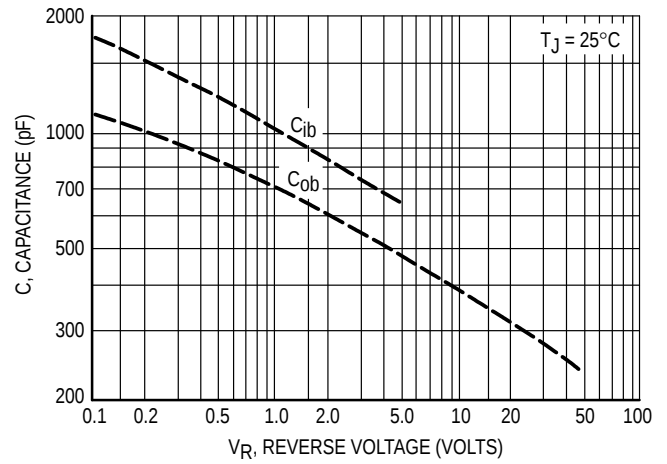


Figure 7. Capacitance

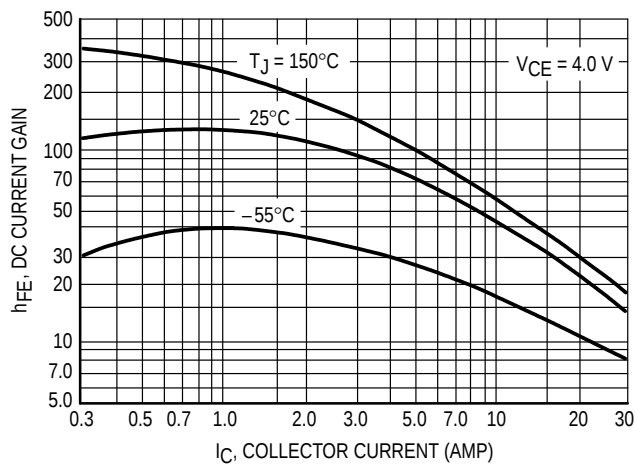


Figure 8. DC Current Gain

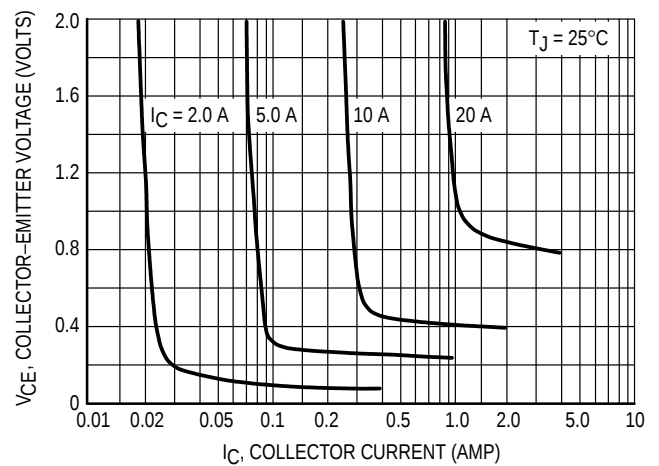
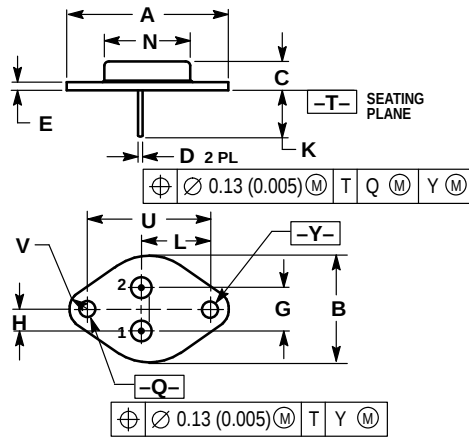


Figure 9. Collector Saturation Region

PACKAGE DIMENSIONS



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	—	1.050	—	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	—	0.830	—	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:

- PIN 1. BASE
- EMITTER
- CASE: COLLECTOR

CASE 1-07
TO-204AA (TO-3)
ISSUE Z

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